User's Guide

TPS51117 Buck Controller Evaluation Module User's Guide



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1 Introduction

1.1 Description

The TPS51117 evaluation module (EVM) is designed to evaluate the performance and characteristics of Tl's cost-optimized, D-CAP™ mode, synchronous buck TPS51117 controller. The evaluation module uses 6-V to 21-V input and delivers 1.05-V output at 10 A.

1.2 Features

- Multiple footprint designs support multiple MOSFET configurations
- Abundant test points provide users with great convenience. See Table 2-1.
- Although two TPS51117 package styles are available, the EVM is designed to demonstrate the QFN14 package.

1.3 Operating Specification

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNITS	
Input Characteristics		<u>'</u>		'		
Voltage range (V5IN)	V _{IN}	4.5		5.5	V	
Voltage range (V _{BAT})	V _{IN}	6		21	V	
Output Characteristics		-	'	'		
Output voltage	Configuration of EVM		1.05		V	
Output voltage regulation	Line regulation			0.1%		
	Load regulation			0.3%		
Output voltage ripple	V5IN = 5 V, V _{BAT} = 12 V			35	mVpp	
Output current				10	۸	
Current limit			15		A	
Systems Characteristics						
Switching frequency			350	400	kHz	
Peak efficiency	V5IN = 5 V, V _{BAT} = 12 V, 1.05 V/1 A		89.4%			
Full load efficiency	V5IN = 5 V, V _{BAT} = 12 V, 1.05 V/10 A		82.3%			
Operating temperature			25		°C	

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1.4 Schematic

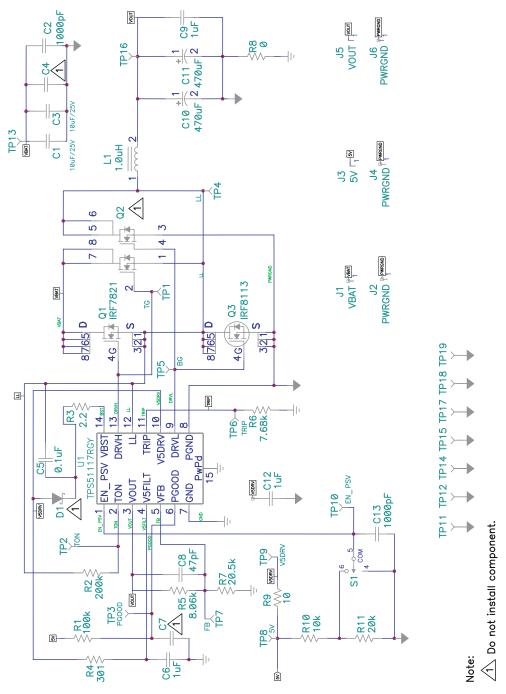


Figure 1-1. TPS51117RGY Evaluation Module (1.05 V at 10 A) Schematic Diagram

Test Setup Www.ti.com

2 Test Setup

2.1 Test Equipment

Voltage Source: Two power supplies are needed, one capable of supplying 21 VDC at 5 A connected at J1 and J2, the other 5 V at 1 A connected at J3 and J4. The minimum recommended wire size is AWG #16 with the total length of wire less than four feet (2-feet input, 2-feet return) to connect the TPS51117 EVM board.

Loads: One electronic load is needed that should be capable of sinking 10 A at 1 V to test specified output and 16 A maximum to test current limit. The minimum recommended wire size is AWG #16 with the total length of wire less than four feet (2-feet input, 2-feet return) to connect the TPS51117 EVM board at J5 and J6.

Meters: Three digital multi-meters are required.

Oscilloscope: A minimum 50-MHz digital oscilloscope with one voltage probe is required.

2.2 Test Points

Table 2-1. Test Point Functions

TEST POINTS	NAME	DESCRIPTION
TP1	DRVH	High-side gate drive
TP2 (NP)	TON	On-time / frequency measurement
TP3	PGOOD	Power good
TP4	LL	High-side gate driver return / anode for overcurrent comparator
TP5	DRVL	Low-side gate drive
TP6	TRIP	Overcurrent trip point set input
TP7 (NP)	FB	Feedback input
TP8	5V	5-V supply voltage
TP9	V5DRV	5-V power supply input for FET gate drivers
TP10	EN_PSV	Enable power save
TP11 (NP)	GND	Ground
TP12	GND	Ground
TP13	VBAT	V _{IN} supply voltage
TP14	GND	Ground
TP15	GND	Ground
TP16	VOUT	Output voltage
T17	GND	Ground
TP18	GND	Ground
TP19 (NP)	GND	Ground

Test Setup

2.3 Recommended Test Setup

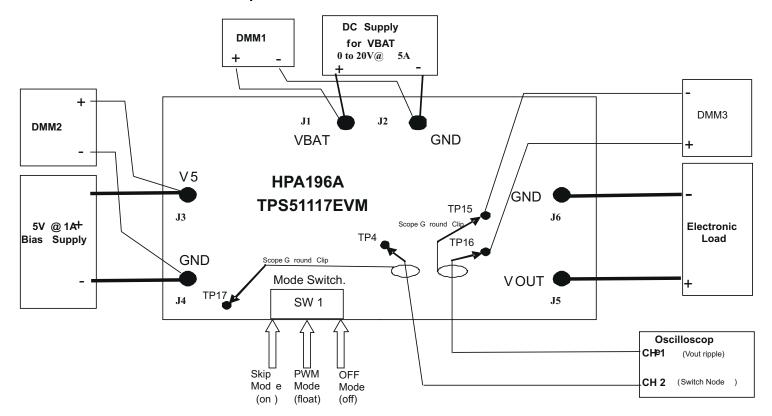


Figure 2-1. Test Setup

Figure 2-1 shows the recommended test setup to evaluate the TPS51117EVM. Working at an ESD workstation, make sure that any wrist straps or mats are connected referencing the user-to-earth ground before power is applied to the EVM.

Test Setup www.ti.com

2.4 Standard Test Procedures

2.4.1 Line/Load Regulation

- 1. Ensure the load is set to constant current mode and set to 0 A_{DC}.
- 2. Make sure the switch SW 1 is in the "OFF" position.
- 3. Turn on V_{BAT} supply, increase to 12 V, and use DMM1 to measure the voltage.
- 4. Turn on 5.0-V bias supply, increase to 5 V, and use DMM2 to measure the voltage.
- 5. Turn on SW1 to skip mode (On) and verify output voltage on DMM3.
- 6. Vary the load from 0 A_{DC} to 10 $A_{DC}.\ V_{OUT}$ should remain in load regulation.
- 7. Move the SW1 to PWM mode (float) and repeat step 6.
- 8. With load still at 10 A_{DC}, vary the V_{BAT} supply from 6 V to 21 V. V_{OUT} should remain in line regulation.
- 9. Turn SW1 to the OFF position. Verify V_{OUT} is 0 V.
- 10. Decrease the load to 0 A.
- 11. Decrease bias supply and V_{BAT} supply to 0 V.

2.4.2 Output Ripple Measurement

- 1. Ensure the load is set to constant current mode and set to 0 A_{DC}.
- 2. Make sure the switch SW 1 is in the "OFF" position.
- 3. Turn on V_{BAT} supply, increase to 12 V, and use DMM1 to measure the voltage.
- 4. Turn on the 5.0-V bias supply, increase to 5 V, and use DMM2 to measure the voltage.
- 5. Set the load to 10 A_{DC}.
- 6. Attach an oscilloscope probe to TP16 and ground to TP15.
- 7. Set the oscilloscope as follows:
 - a. Horizontal sweep: 2 µs/div
 - b. Trigger mode: auto, falling edge
 - c. Channel should be set to AC coupled, bandwidth 20 Mhz

Measurement should be similar to Figure 3-5.

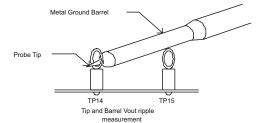
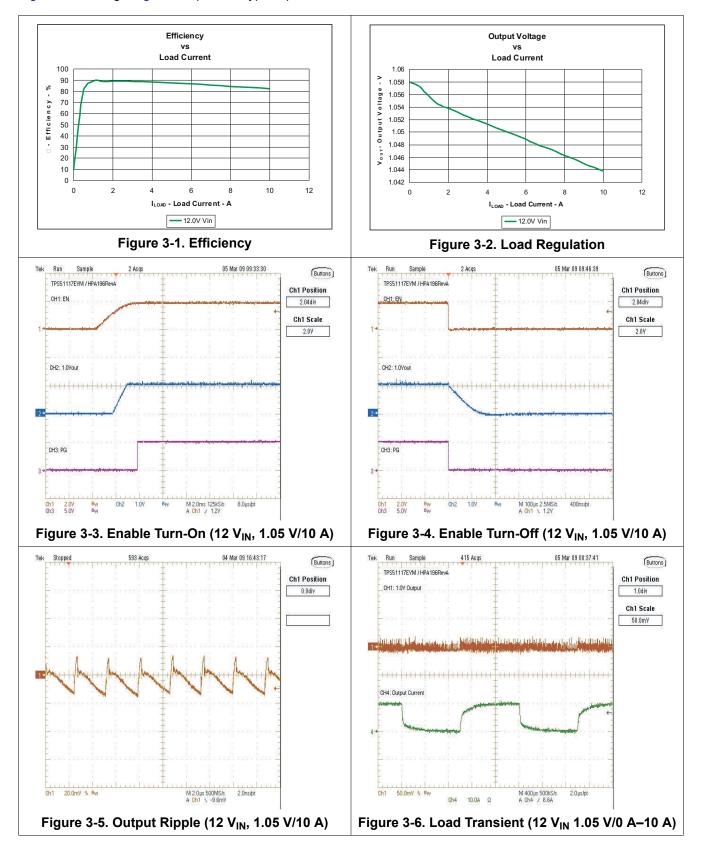


Figure 2-2. Tip and Barrel Measurement for V_{OUT} Ripple



3 Performance Data and Typical Characteristic Curves

Figure 3-1 through Figure 3-6 present typical performance curves for TPS51117EVM-001.





4 Board Layout Using TPS51117RGY (QFN 14)

Figure 4-1 through Figure 4-4 show the design of the TPS51117EVM printed circuit board. The EVM has been designed using four layers on a two-ounce copper circuit board.

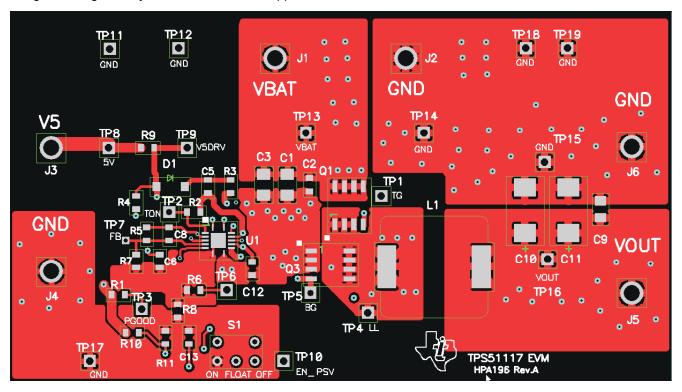


Figure 4-1. Top Layer Copper

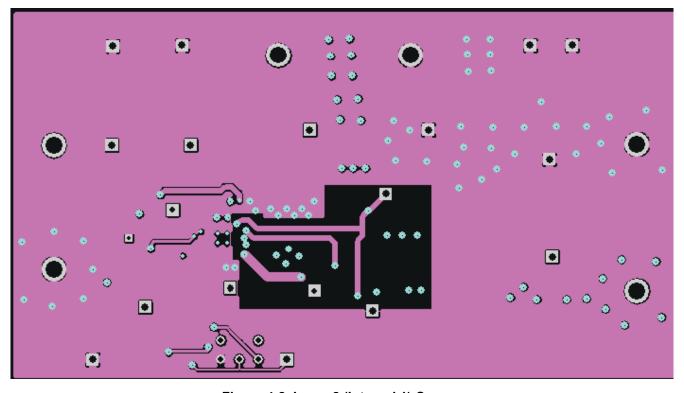


Figure 4-2. Layer 2 (Internal 1) Copper

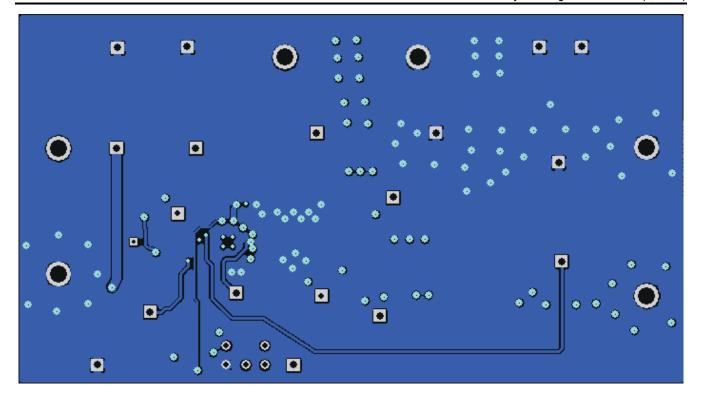


Figure 4-3. Layer 3 (Internal 2) Copper

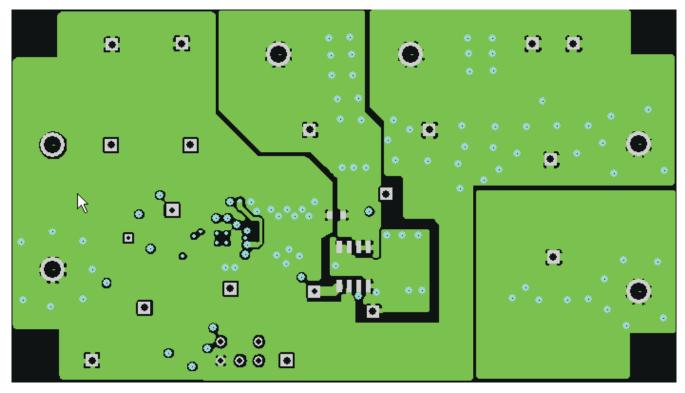


Figure 4-4. Bottom Layer Copper

List of Materials www.ti.com

5 List of Materials

The TPS51117EVM List of Materials.

Table 5-1. List of Materials

REFDES	PATTERN NAME	VALUE	PART NUMBER	MFR
EVM Configur	ration 1.05 V at 10 A BOM			
C5	C603	0.1 µF	VJ0603Y104KXXAC	Vishay
C12, C6	C603	1 μF, 16 V	C1608X7R1C105K	TDK
C8	C603	47 pF	VJ0603A470JXAAC	Vishay
C2, C13	C603	1000 pF	VJ0603Y102KXAAC	Vishay
C4	C603	Not Installed	VJ0603Y102KXAAC	Vishay
C7	C603	Not Installed	VJ0603Y103KXAAC	Vishay
C9	C0805	1 μF, 25 V	C2012X7R1E105K	TDK
C1, C3	C1206	10 μF, 25 V	ECJ-3YB1E106K	Panasonic
C10, C11	CAP_POSCAP_D	470 μF	2R5TPE470MC	Sanyo
J3	HEADER_8952	5 V	1582-2	Keystone
J2	HEADER_8952	PWRGND	1582-2	Keystone
J4	HEADER_8952	PWRGND	1582-2	Keystone
J6	HEADER_8952	PWRGND	1582-2	Keystone
J1	HEADER_8952	VBAT	1582-2	Keystone
J5	HEADER_8952	VOUT	1582-2	Keystone
D1	SOD-123	Not Installed	MBR0530Tx	On Semi
Q2	SO8	Not Installed	Si4944DY	Siliconix
L1	IND_IHLP-5050	1.0 µH	IHLP5050CEER1R0M01	Vishay
Q1	SO8	IRF7821	IRF7821	IR
Q3	SO8	IRF8113	IRF8113	IR
R8	R603	0 Ω	STD	Vishay
R3	R603	2.21 Ω	STD	Vishay
R6	R603	7.68 kΩ	STD	Vishay
R5	R603	8.06 kΩ	STD	Vishay
R9	R603	10 Ω	STD	Vishay
R4	R603	301 Ω	STD	Vishay
R10	R603	10 kΩ	STD	Vishay
R11	R603	20 kΩ	STD	Vishay
₹7	R603	20.5 kΩ	STD	Vishay
R1	R603	100 kΩ	STD	Vishay
R2	R603	200 kΩ	CRCW06032003FKTA	Vishay
S1	SW_1P3T	G13AP	G13AP	NKK
U1	QFN14	TPS51117RGY	TPS51117RGY	TI

6 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision A (April 2009) to Revision B (February 2022)		
•	Updated the numbering format for tables, figures, and cross-references throughout the document	2
•	Updated the user's guide title	<mark>2</mark>

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